

Atty Dkt. No. ONS00505

SHEET 1 OF 4

0N500505 HADIZAD

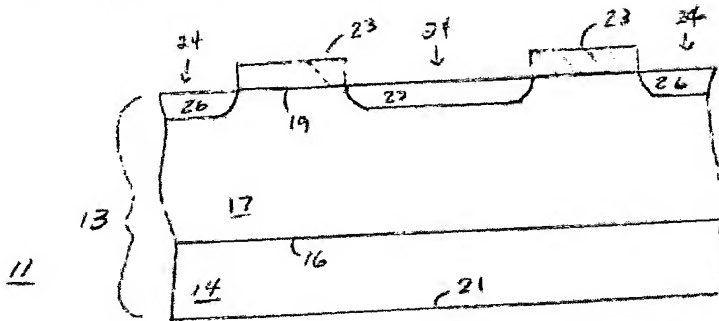


FIG. 1

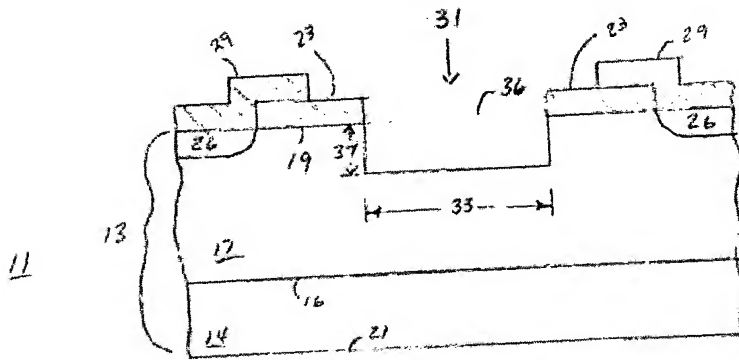


FIG. 2

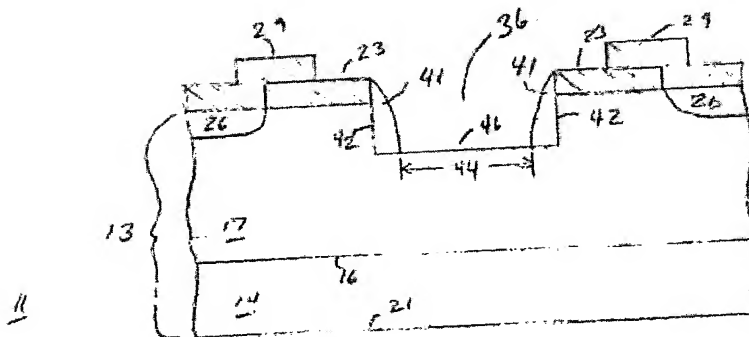
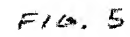
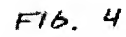


Fig. 3

Atty Dkt. No. ONS00505 SHEET 2 OF 4

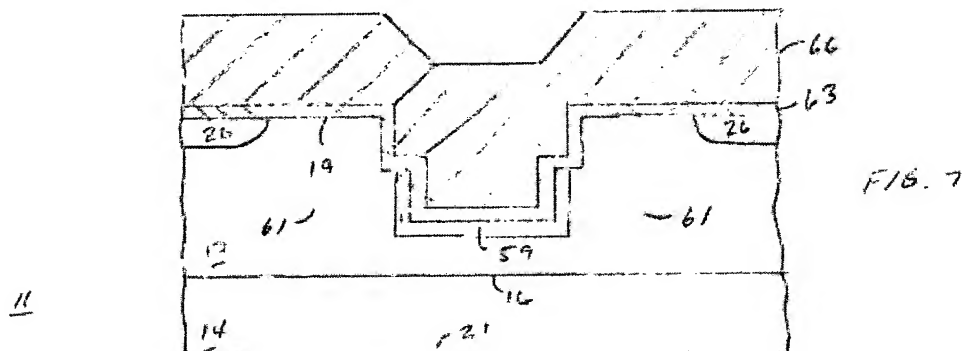
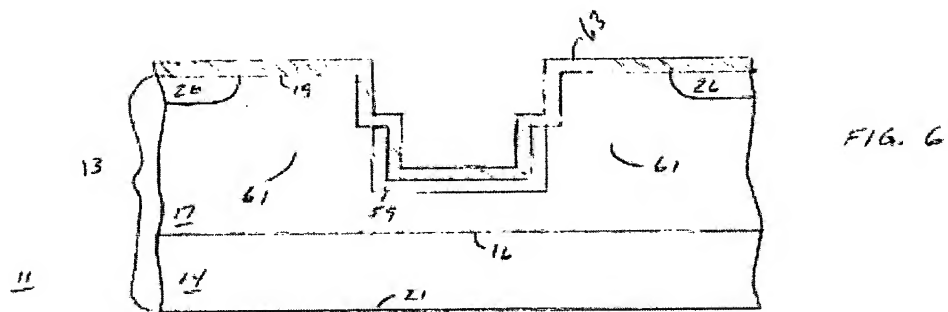
11



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METHOD OF MAKING A VERTICAL COMPOUND
SEMICONDUCTOR FIELD EFFECT TRANSISTOR DEVICE
Atty Dkt. No. ONS00505 SHEET 3 OF 4

ONS00505 HADIZAD



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Atty Dkt. No. ONS00505 SHEET 4 OF 4

ONS00505 HADIZAD

